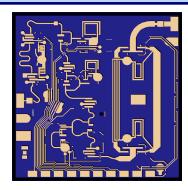


# 8.5 - 11 GHz 6-bit Phase Shifter



### **Primary Applications**

- Military Radar
- Transmit / Receive

### Description

The TriQuint TGP2103 is a 6-bit digital phase shifter MMIC design using TriQuint's proven 0.5µm MESFET process. The TGP2103 will support a variety of X-Band phased array applications including military radar.

The 6-bit design utilizes a compact topology that achieves a 11.31mm<sup>2</sup> die area and high performance.

The TGP2103 provides a 6-bit digital phase shift function with a nominal 5dB insertion loss and 2° RMS phase shift error over a bandwidth of 8.5-11GHz.

The TGP2103 requires a minimum of offchip components and operates with a -5V control voltage. Each device is RF tested on-wafer to ensure performance compliance. The device is available in chip form.

Lead-Free and RoHS compliant

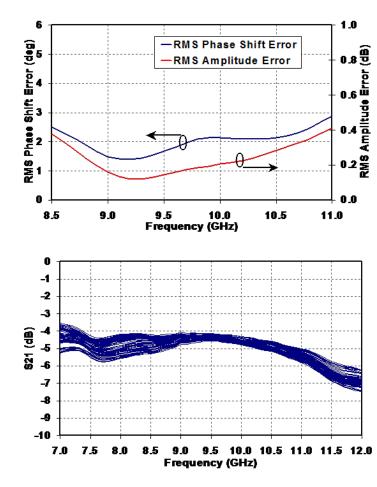
Datasheet subject to change without notice

### **Key Features and Performance**

- Frequency Range: 8.5 11 GHz
- 5dB Nominal Insertion Loss
- 2deg RMS Phase Error @ 9.5GHz
- 0.2dB RMS Amp. Error @ 9.5GHz
- Negative Control Voltage
- 0.5µm MESFET Technology
- Chip dimensions:

3.25 x 3.48 x 0.15 mm (0.128 x 0.137 x 0.006 inches)

### **Measured Performance**





#### TABLE I MAXIMUM RATINGS

Symbol	Parameter	Value	Notes
Vc	Control Voltage Range	-8V to 0V	<u>1/ 2</u> /
Ι <sub>C</sub>	Control Supply Current	1 mA	<u>1/ 2</u> /
P <sub>IN</sub>	Input Continuous Wave Power	20 dBm	<u>1/ 2</u> /
PD	Power Dissipation	0.1 W	<u>1/ 2</u> /
T <sub>CH</sub>	Operating Channel Temperature	200 °C	<u>3</u> /
	Mounting Temperature (30 Seconds)	320 °C	
T <sub>STG</sub>	Storage Temperature	-65 to 150 °C	

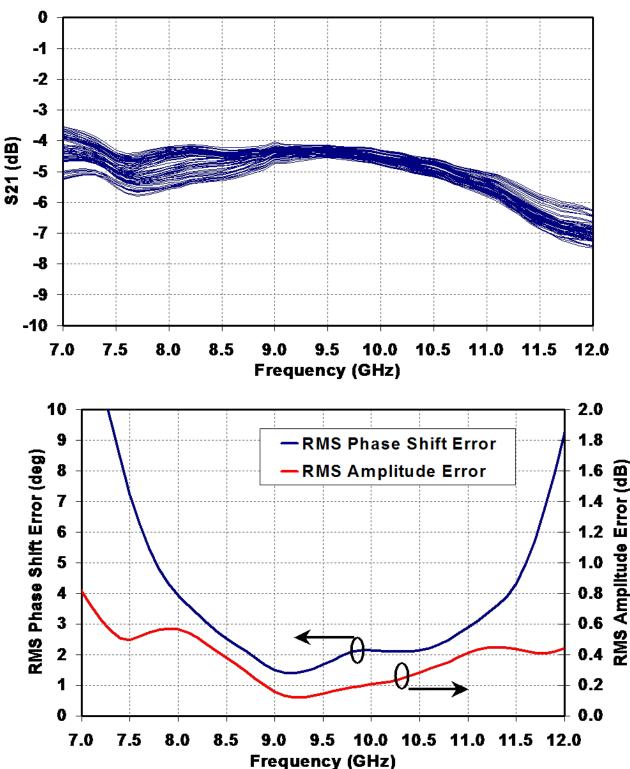
- 1/ These ratings represent the maximum operable values for this device
- 2/ Combinations of supply voltage, supply current, input power, and output power shall not exceed P<sub>D</sub>
- Junction operating temperature will directly affect the device median time to failure (Tm). For maximum life, it is recommended that junction temperatures be maintained at the lowest possible levels.

#### TABLE II RF CHARACTERIZATION TABLE $(T_A = 25^{\circ}C, Nominal)$ $(V_C = -5V)$

Parameter	Test Conditions	Тур	Units	Notes
Insertion Loss	8.5 – 11GHz	5	dB	
Peak Amplitude Error	8.5 – 11GHz	0.5	dB	
RMS Amplitude Error	8.5 – 11GHz	0.2	dB	
Peak Phase Shift Error	8.5 – 11GHz	3	deg	
RMS Phase Shift Error	8.5 – 11GHz	2	deg	
Input Return Loss	8.5 – 11GHz	15	dB	
Output Return Loss	8.5 – 11GHz	12	dB	

Note: Table II Lists the RF Characteristics of typical devices as determined by fixtured measurements.





### **Preliminary Measured Data**

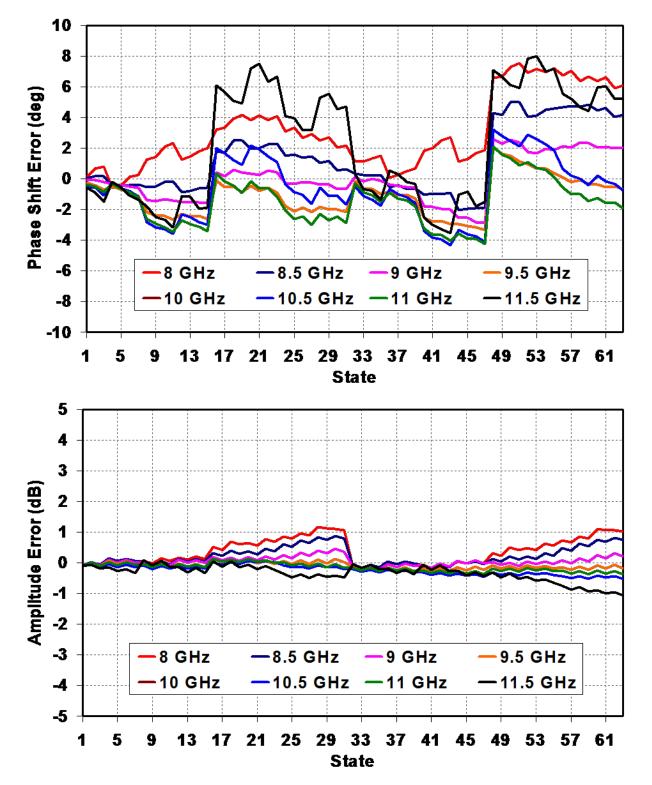


#### 0 -3 -6 -9 -12 S11 (dB) -15 -18 -21 -24 -27 -30 11.5 7.5 8.5 9.0 10.5 11.0 7.0 8.0 9.5 10.0 12.0 Frequency (GHz) 0 -3 -6 -9 -12 S22 (dB) -15 -18 -21 -24 -27 -30 7.0 8.0 8.5 9.0 9.5 10.0 10.5 11.0 11.5 12.0 7.5 Frequency (GHz)

### **Preliminary Measured Data**

**TGP2103** 





### **Preliminary Measured Data**

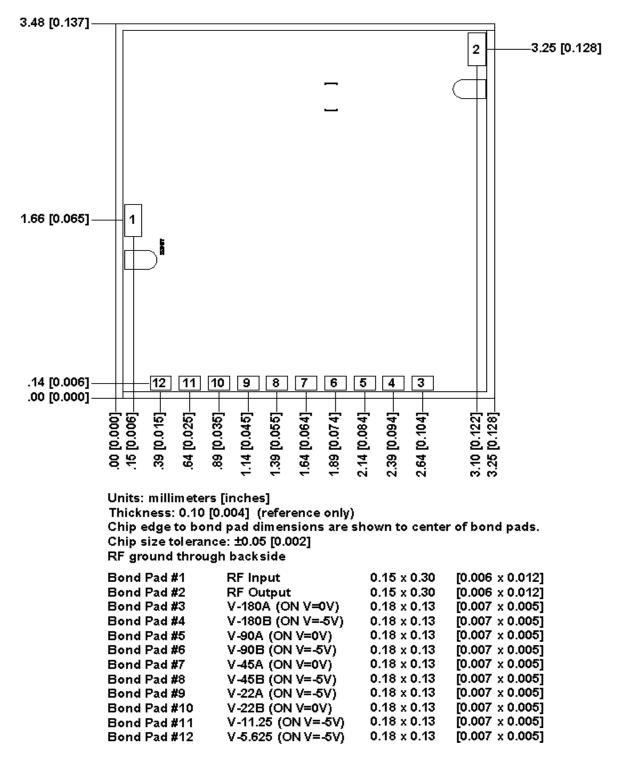


#### **State Table**

State	V-5.625	V-11.25	V-22.5A	V-22.5B	V-45A	V-45B	V-90A	V-90B	V-180A	V-180B	Phase Shift
0	OV	0V	0V	-5V	-5V	٥V	-5V	OV	-5V	0۷	Reference
1	-5V	OV	OV	-5V	-5V	٥v	-5V	OV	-5V	0V	5.625°
2	OV	-5V	0V	-5V	-5V	٥v	-5V	OV	-5V	0V	11.25*
3	-5V	-5V	0V	-5V	-5V	0V	-5V	0V	-5V	0V	16.875°
4	OV	0V	-5V	0V	-5V	OV	-5V	OV	-5V	OV	22.5°
5	-5V	OV	-5V	OV	-5V	OV	-5V	OV	-5V	0V	28.125°
6	0V	-5V	-5V	0V	-5V	0V	-5V	07	-5V	0V	33.75*
7	-5V	-5V	-5V	0V	<u>-5V</u>	0V	-5V	0V	-5V	<u>0V</u>	39.375*
8	0V	OV OV	OV OV	-5V	0V 0V	-5V	-5V	0V 0V	-5V	0V	45* 50.625*
9 10	-5V 0V	-5V	0V 0V	-5V -5V	0V 0V	-5V -5V	-5V -5V	0V 0V	-5V	0V 0V	
11	-5V	-3v -5V	0V 0V	-3V -5V	0V 0V	-5V -5V	-3v -5V	0V 0V	-5V -5V	07	56.25* 61.875*
12	 0V	-34	-5V	 0V	07	-5V	-5V	0V	-3V -5V	0V	67.5*
13	-5V	ov	-57	OV	0V	-5V	-57	ov	-5V	OV	73.125*
14	0V	-5V	-57	OV	ov	-5V	-5V	ov	-5V	OV	78.75°
15	-5V	-5V	-5V	ov	οv	-5V	-5V	ÖV	-5V	OV	84.375°
16	07	0V	07	-5V	-5V	0V	0V	-5V	-5V	07	90*
17	-5V	ov	ov	-5V	-5V	OV	OV	-5V	-5V	ΟV	95.625°
18	OV	-5V	OV	-5V	-5V	ov	OV	-5V	-5V	OV	101.25*
19	-5V	-5V	OV	-5V	-5V	OV	OV	-5V	-5V	OV	106.875*
20	٥V	0۷	-5V	0٧	-5V	٥V	٥V	-5V	-5V	0۷	112.5°
21	-5V	0V	-5V	0V	-5V	0V	0V	-5V	-5V	OV	118.125°
22	0V	-5V	-5V	OV	-5V	0V	0V	-5V	-5V	0V	123.75°
23	-5V	-5V	-5V	0V	-5V	0V	٥v	-5V	-5V	0V	129.375*
24	OV	OV	0V	-5V	OV	-5V	٥V	-5V	-5V	OV	135*
25	-5V	OV	0V	-5V	OV	-5V	0V	-5V	-5V	OV	140.625*
26	OV	-5V	OV	-5V	OV	-5V	OV	-5V	-5V	0V	146.25°
27	-5V	-5V	0V	-5V	0V	-5V	0V	-5V	-5V	0V	151.875*
28	OV	OV	-5V	0V	0V	-5V	OV	-5V	-5V	07	157.5*
29	-5V	OV	-5V	0V	0V	-5V	0V	-5V	-5V	0V	163.125*
30	0V	-5V	-5V	0V	0V	-5V	0V	-5V	-5V	0V	168.75*
31 32	-5V 0V	-5V 0V	-5V 0V	<u>0v</u> -5V	0V -5V	-5V 0V	<u>0v</u> -5v	-5V 0V	-5V 0V	0V -5V	174.375* 180*
33	-5V	0V 0V	0V 0V	-5V -5V	-5V	0V 0V	-3V -5V	0V 0V	0V 0V	-5V -5V	185.625*
33 34	-3V OV	-5V	OV	-5V -5V	-5V	OV	-5V	0V	OV	-5V -5V	191.25*
35	-5V	-5V	ov	-5V	-5V	OV	-5V	ov	ov	-5V	196.875°
36	07	0V	-5V	0V	-5V	07	-5V	0V	07	-5V	202.5*
37	-5V	OV	-5V	ov	-5V	OV	-5V	οv	OV	-5V	208.125*
38	ov	-5V	-5V	OV	-5V	OV	-5V	ΟV	OV	-5V	213.75*
39	-5V	-5V	-5V	OV	-5V	ov	-5V	ov	OV	-5V	219.375*
40	OV	OV	OV	-5V	OV	-5V	-5V	OV	OV	-5V	225*
41	-5V	OV	0V	-5V	OV	-5V	-5V	OV	0V	-5V	230.625*
42	٥V	-5V	0V	-5V	0V	-5V	-5V	OV	٥V	-5¥	236.25°
43	-5V	-5V	0V	-5V	OV	-5V	-5V	OV	OV	-5V	241.875*
44	OV	0V	-5V	0V	0V	-5V	-5V	OV	0V	-5V	247.5°
45	-5V	0V	-5V	0V	0V	-5V	-5V	OV	0V	-5V	253.125*
46	OV	-5V	-5V	0V	OV	-5V	-5V	OV	OV	-5V	258.75°
47	-5V	-5V	-5V	OV	OV	-5V	-5V	٥V	0V	-5V	264.375*
48	OV	0V	0V	-5V	-5V	OV	OV	-5V	0V	-5V	270*
49	-5V	0V	0V	-5V	-5V	0V	OV	-5V	0V	-5V	275.625*
50	OV	-5V	OV	-5V	-5V	0V	07	-5V	07	-5V	281.25°
51	-5V	-5V	<u> 0V</u>	-5V	<u>-5V</u>	<u>0V</u>	<u>0V</u>	-5V	<u>0V</u>	-5V	286.875*
52 52	07	0V	-5V	0V	-5V	0V	0V	-5V	0V	-5V	292.5°
53 54	-5V	0V	-5V	0V	-5V	0V 0V	0V 0V	-5V	0V	-5V	298.125°
54 55	0V	-5V	-5V ਙv	0V 0V	-5V	0V 0V	0V 0V	-5V	0V 0V	-5V	303.75°
<u>55</u> 56	<u>-5V</u> 0V	<u>-5V</u> 0V	<u>-5V</u> 0V	<u>0V</u> -5V	<u>-5V</u> 0V	<u>0V</u> -5V	0V 0V	<u>-5V</u> -5V	0V 0V	<u>-5V</u> -5V	<u>309.375*</u> 315*
57 58	-5V 0V	0V -5V	OV OV	-5V -5V	0V 0V	-5V -5V	0V 0V	-5V -5V	0V 0V	-5V -5V	320.625* 326.25*
59	-5V	-3V -5V	0V 0V	-5V -5V	0V 0V	-5V	0V 0V	-3¥ -5¥	0V 0V	-5V -5V	320.25 331.875*
<u> </u>	-37	-34	-5V	- <u>JV</u> 0V	07	-5V	0V	-5V	0V	-5V -5V	337.5*
61	-5V	OV	-57	OV	0V	-5V	OV	-5V	ov	-5V	343.125°
62	-3V OV	-5V	-5V	οv	0V	-5V	OV	-5V	ov	-5V	348.75*
63	-5V	-5V	-5V	οv	οv	-5V	OV	-57	OV	-5V	354.375*
	31	31	31	- •	- •	31		31	~ •		



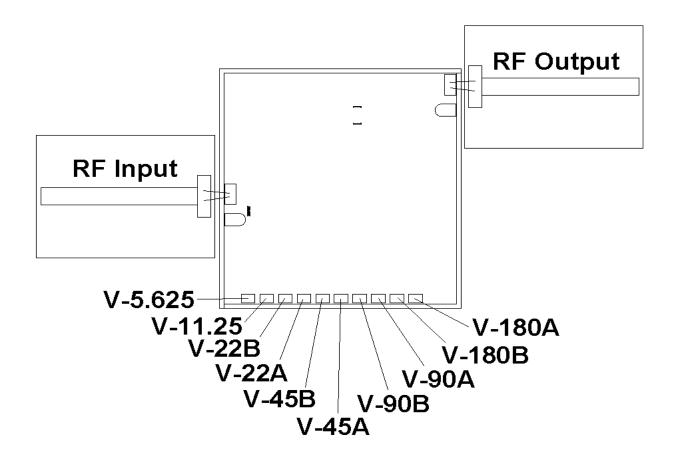
**Mechanical Drawing** 











- Devices were tested with 500 $\Omega$  resistors in series with control lines

- Input and output stubs are 0.010" x 0.025" on 0.010" alumina substrate

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



## Assembly Process Notes

Reflow process assembly notes:

- Use AuSn (80/20) solder with limited exposure to temperatures at or above 300°C. (30 seconds maximum)
- An alloy station or conveyor furnace with reducing atmosphere should be used.
- No fluxes should be utilized.
- Coefficient of thermal expansion matching is critical for long-term reliability.
- Devices must be stored in a dry nitrogen atmosphere.

Component placement and adhesive attachment assembly notes:

- Vacuum pencils and/or vacuum collets are the preferred method of pick up.
- Air bridges must be avoided during placement.
- The force impact is critical during auto placement.
- Organic attachment can be used in low-power applications.
- Curing should be done in a convection oven; proper exhaust is a safety concern.
- Microwave or radiant curing should not be used because of differential heating.
- Coefficient of thermal expansion matching is critical.

Interconnect process assembly notes:

- Thermosonic ball bonding is the preferred interconnect technique.
- Force, time, and ultrasonics are critical parameters.
- Aluminum wire should not be used.
- Maximum stage temperature is 200°C.

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